NSN 5962-01-554-3770

Memory Microcircuit - Page 1 of 1



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Operating Tempurature Range:
+0.0/+85.0 degrees celsius
Features Provided:
Low power and w/clock and 3-state output
Inclosure Material:
Plastic
Inclosure Configuration:
Flat pack
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Current Rating Per Characteristic:
500.00 milliamperes forward current, nonrepetitive, peak total value absolute
Product Name:
Field programmable gate array
Voltage Rating And Type Per Characteristic:
1.8 volts total supply
Time Rating Per Chacteristic:
6.00 nanoseconds delay
Memory Device Type:
Ram
Memory Capacity:
64 x 96
Terminal Type And Quantity:
240 flat leads
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:
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